



## UNITED STATES PATENT AND TRADEMARK OFFICE

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UNITED STATES PATENT AND TRADEMARK OFFICE  
WASHINGTON, D.C. 20590  
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Bib Data Sheet

CONFIRMATION NO. 7221

<b>SERIAL NUMBER</b> 10/039.196	<b>FILING DATE</b> 01/02/2002 <b>RULE</b>	<b>CLASS</b> <del>417</del> 428	<b>GROUP ART UNIT</b> <del>1765</del> 1772	<b>ATTORNEY DOCKET NO.</b> MEMC 00-1400 (2806.1)
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## APPLICANTS

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## \*\* CONTINUING DATA \*\*\*\*\*

THIS APPLN CLAIMS BENEFIT OF 60/259,362 01/02/2001

yes *GR*

## \*\* FOREIGN APPLICATIONS \*\*\*\*\*

none *GR*

## IF REQUIRED, FOREIGN FILING LICENSE GRANTED

\*\* 01/28/2002

Foreign Priority claimed <input type="checkbox"/> yes <input checked="" type="checkbox"/> no	STATE OR COUNTRY UNITED KINGDOM	SHEETS DRAWING 17	TOTAL CLAIMS 59	INDEPENDENT CLAIMS 3
35 USC 119 (a-d) conditions met <input type="checkbox"/> yes <input checked="" type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
Verified and Acknowledged Examiner's Signature <i>[Signature]</i> Initials <i>[Initials]</i>				

## ADDRESS

000321

## TITLE

Process for preparing single crystal silicon having improved gate oxide integrity

<b>FILING FEE RECEIVED</b> 2356	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> All Fees
		<input type="checkbox"/> 1.16 Fees ( Filing )
		<input type="checkbox"/> 1.17 Fees ( Processing Ext. of time )
		<input type="checkbox"/> 1.18 Fees ( Issue )
		<input type="checkbox"/> Other _____
		<input type="checkbox"/> Credit _____